

SAR Evaluation Report

IN ACCORDANCE WITH THE REQUIREMENTS OF FCC OET BULLETIN 65 SUPPLEMENT C IC RSS 102 ISSUE 2 : NOVERMBER 2005

FOR

VOIP MOBILE PHONE TERMINAL

MODEL: WLPS3(E)-A

FCC ID: EW4-WLPS3-1 IC: 4250A-WLPS3

REPORT NUMBER: 07J11502-3B

ISSUE DATE: FEBUARY 5, 2008

Prepared for

MITSUMI ELECTRIC CO., LTD 1601 SAKAI, ATSUGI-SHI, KANAGAWA, 243-8533, JAPAN

Prepared by

COMPLIANCE CERTIFICATION SERVICES 47173 BENICIA STREET, FREMONT, CA 94538 USA



NVLAP LAB CODE 200065-0

DATE: February 7, 2008

Revision History

Rev.	Issued date	Revisions	Revised By
	2-1-08	Initial issue	Hsin Fu Shih
В	2-7-08	Removed note from p. 23 and updated FCC ID on p.1	J. King

CERTIFICATE OF COMPLIANCE (SAR EVALUATION)

DATES OF TEST: January 31, 2008					
APPLICANT:	MITSUMI ELECTRIC CO., LTD				
ADDRESS:	1601 SAKAI, ATSUGI-SHI,				
	KANAGAWA, 243-8533, JAPAN				
FCC ID:	EW4-WLPS3-1				
MODEL:	WLPS3(E)-A				
DEVICE CATEGORY:	Portable Device				
EXPOSURE CATEGORY:	General Population/Uncontrolled Exposure				

VOIP MOBILE PHONE TERMINAL						
Test Sample is a:	Production unit					
Modulation type:	Direct Sequence Spread Spectrum (DSSS) for 802.11b					
Rule Parts	Frequency Range [MHz]	The Highest SAR Values [1g_mW/g]				
FCC 15.247	2412 - 2462	Head Positions: Body Positions:	0.453 1.457			

This wireless portable device has been shown to be capable of compliance for localized specific absorption rate (SAR) for General Population/Uncontrolled Exposure limits specified in ANSI/IEEE Std. C95.1-1992 and had been tested in accordance with the measurement procedures specified in FCC OET 65 Supplement C (Edition 01-01) and RSS 102.

Note: The results documented in this report apply only to the tested sample, under the conditions and modes of operation as described herein. This document may not be altered or revised in any way unless done so by Compliance Certification Services and all revisions are duly noted in the revisions section. Any alteration of this document not carried out by Compliance Certification Services will constitute fraud and shall nullify the document. No part of this report may be used to claim product certification, approval, or endorsement by NVLAP, NIST, or any government agency.

Approved & Released For CCS By:

sin-Fa Shih

Hsin Fu Shih Engineering Supervisor Compliance Certification Services

Tested By:

Jonathan King

Jonathan King EMC Engineer Compliance Certification Services

TABLE OF CONTENTS

1	DE\	/ICE UNDER TEST (DUT) DESCRIPTION	5
2	FAC	CILITIES AND ACCREDITATION	6
3	SYS	STEM DESCRIPTION	7
	3.1	COMPOSITION OF INGREDIENTS FOR TISSUE SIMULATING LIQUIDS	8
4	TES	T POSITIONS FOR DEVICES OPERATING NEXT TO A PERSON'S EAR	9
	4.1	CHEEK/TOUCH POSITION	10
	4.2	EAR/TILT POSITION	11
	4.3	TEST POSITIONS FOR BODY-WORN AND OTHER SIMILAR CONFIGURATIONS	12
5	SIM	ULATING LIQUID PARAMETERS CHECK	13
	5.1	SIMULATING LIQUID PARAMETER CHECK RESULT	14
6	SYS	STEM PERFORMANCE CHECK	16
	6.1	SYSTEM PERFORMANCE CHECK RESULTS	17
7	SAF	R MEASURMENT PROCEDURE	18
	7.1	DASY4 SAR MEASURMENT PROCEDURE	19
8	PRO	DCEDURE USED TO ESTABLISH TEST SIGNAL	20
9	SAF	R MEASURMENT RESULTS	21
	9.1	HEAD POSITIONS - LEFT HAND SIDE (LHS)	21
	9.2	HEAD POSITIONS - RIGHT HAND SIDE (RHS)	22
	9.3	BODY-WORN POSITION – NO SEPARATION	23
10	ME	ASURMENT UNCERTAINTY	24
	10.1	MEASURMENT UNCERTAINTY FOR 300 MHZ – 3000 MHZ	24
11	EQI	JIPMENT LIST AND CALIBRATION	25
12	PHC	DTOS	26
13	ATT	ACHMENTS	28

1 DEVICE UNDER TEST (DUT) DESCRIPTION

VOIP MOBILE PHONE TE	VOIP MOBILE PHONE TERMINAL						
Normal operation:	Head and body worn	positions					
Accessories:	Headset Jack						
Duty cycle:	100%						
Antenna(s)	Main Antenna: Sub Antenna: Note: Only the Main /	Mitsumi Electric Co., LTD. Model DCA-P09 Mitsumi Electric Co., LTD. Model DCA-P07 Antenna was used for the SAR testing.					
Battery:	Manufacturer: Model No.:	NEC Tokin Corp. CBG-002535-202, 3.7Vdc, 850mAh, Li-Ion Battery					

2 FACILITIES AND ACCREDITATION

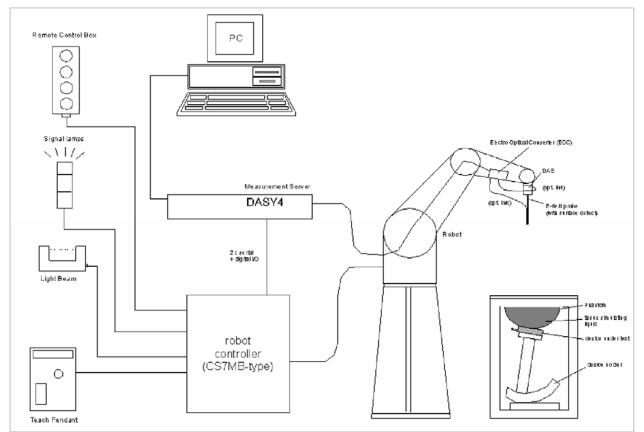
The test sites and measurement facilities used to collect data are located at 47173 Benicia Street, Fremont, CA 94538 USA. The sites are constructed in conformance with the requirements of ANSI C63.4, ANSI C63.7 and CISPR Publication 22. All receiving equipment conforms to CISPR Publication 16-1, "Radio Interference Measuring Apparatus and Measurement Methods."

NVLAP LAB CODE 200065-0

CCS is accredited by NVLAP, Laboratory Code 200065-0. The full scope of accreditation can be viewed at http://www.ccsemc.com.

No part of this report may be used to claim product certification, approval, or endorsement by NVLAP, NIST, or any government agency.

3 SYSTEM DESCRIPTION



The DASY4 system for performing compliance tests consists of the following items:

- A standard high precision 6-axis robot (Stäubli RX family) with controller, teach pendant and software. An arm extension for accommodating the data acquisition electronics (DAE).
- A dosimetric probe, i.e., an isotropic E-field probe optimized and calibrated for usage in tissue simulating liquid. The probe is equipped with an optical surface detector system.
- A data acquisition electronics (DAE) which performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. The unit is battery powered with standard or rechargeable batteries. The signal is optically transmitted to the EOC.
- The function of the measurement server is to perform the time critical tasks such as signal filtering, control of the robot operation and fast movement interrupts.
- A probe alignment unit which improves the (absolute) accuracy of the probe positioning.
- A computer operating Windows 2000 or Windows XP.
- DASY4 software.
- Remote controls with teach pendant and additional circuitry for robot safety such as warning lamps, etc.
- The SAM twin phantom enabling testing left-hand and right-hand usage.
- The device holder for handheld mobile phones.
- Tissue simulating liquid mixed according to the given recipes.
- Validation dipole kits allowing to validate the proper functioning of the system.

3.1 COMPOSITION OF INGREDIENTS FOR TISSUE SIMULATING LIQUIDS

The following tissue formulations are provided for reference only as some of the parameters have not been thoroughly verified. The composition of ingredients may be modified accordingly to achieve the desired target tissue parameters required for routine SAR evaluation.

Ingredients		Frequency (MHz)								
(% by weight)	45	50	83		· 9′			00	2450	
Tissue Type	Head	Body	Head	Body	Head	Body	Head	Body	Head	Body
Water	38.56	51.16	41.45	52.4	41.05	56.0	54.9	40.4	62.7	73.2
Salt (NaCl)	3.95	1.49	1.45	1.4	1.35	0.76	0.18	0.5	0.5	0.04
Sugar	56.32	46.78	56.0	45.0	56.5	41.76	0.0	58.0	0.0	0.0
HEC	0.98	0.52	1.0	1.0	1.0	1.21	0.0	1.0	0.0	0.0
Bactericide	0.19	0.05	0.1	0.1	0.1	0.27	0.0	0.1	0.0	0.0
Triton X-100	0.0	0.0	0.0	0.0	0.0	0.0	0.0	0.0	36.8	0.0
DGBE	0.0	0.0	0.0	0.0	0.0	0.0	44.92	0.0	0.0	26.7
Dielectric Constant	43.42	58.0	42.54	56.1	42.0	56.8	39.9	54.0	39.8	52.5
Conductivity (S/m)	0.85	0.83	0.91	0.95	1.0	1.07	1.42	1.45	1.88	1.78

Salt: 99+% Pure Sodium Chloride

Sugar: 98+% Pure Sucrose

Water: De-ionized, 16 M Ω + resistivity HEC: Hydroxyethyl Cellulose

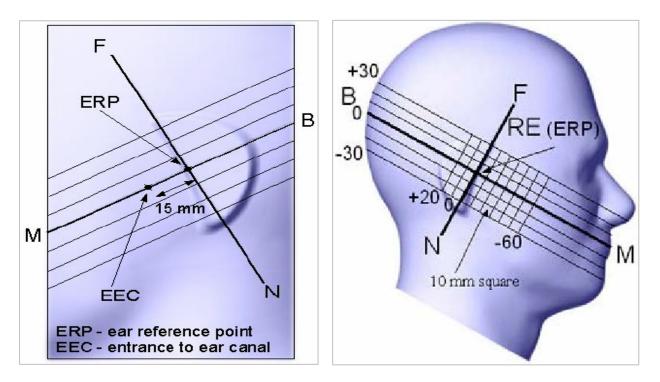
DGBE: 99+% Di(ethylene glycol) butyl ether, [2-(2-butoxyethoxy)ethanol]

Triton X-100 (ultra pure): Polyethylene glycol mono [4-(1,1, 3, 3-tetramethylbutyl)phenyl]ether

4 TEST POSITIONS FOR DEVICES OPERATING NEXT TO A PERSON'S EAR

This category includes most wireless handsets with fixed, retractable or internal antennas located toward the top half of the device, with or without a foldout, sliding or similar keypad cover. The handset should have its earpiece located within the upper ¼ of the device, either along the centerline or off-centered, as perceived by its users. This type of handset should be positioned in a normal operating position with the "test device reference point" located along the "vertical centerline" on the front of the device aligned to the "ear reference point". The "test device reference point" should be located at the same level as the center of the earpiece region. The "vertical centerline" should bisect the front surface of the handset at its top and bottom edges. A "ear reference point" is located on the outer surface of the head phantom on each ear spacer. It is located 1.5 cm above the center of the ear canal entrance in the "phantom reference plane" defined by the three lines joining the center of each "ear reference point" (left and right) and the tip of the mouth.

A handset should be initially positioned with the earpiece region pressed against the ear spacer of a head phantom. For the SCC-34/SC-2 head phantom, the device should be positioned parallel to the "N-F" line defined along the base of the ear spacer that contains the "ear reference point". For interim head phantoms, the device should be positioned parallel to the cheek for maximum RF energy coupling. The "test device reference point" is aligned to the "ear reference point" on the head phantom and the "vertical centerline" is aligned to the "phantom reference plane". This is called the "initial ear position". While maintaining these three alignments, the body of the handset is gradually adjusted to each of the following positions for evaluating SAR:



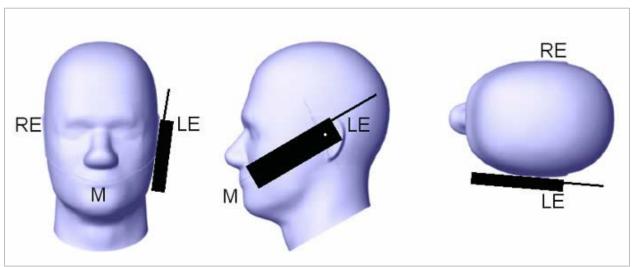
4.1 CHEEK/TOUCH POSITION

The device is brought toward the mouth of the head phantom by pivoting against the "ear reference point" or along the "N-F" line for the SCC-34/SC-2 head phantom.

This test position is established:

- i. When any point on the display, keypad or mouthpiece portions of the handset is in contact with the phantom.
- ii. (or) When any portion of a foldout, sliding or similar keypad cover opened to its intended self-adjusting normal use position is in contact with the cheek or mouth of the phantom.

For existing head phantoms – when the handset loses contact with the phantom at the pivoting point, rotation should continue until the device touches the cheek of the phantom or breaks its last contact from the ear spacer.



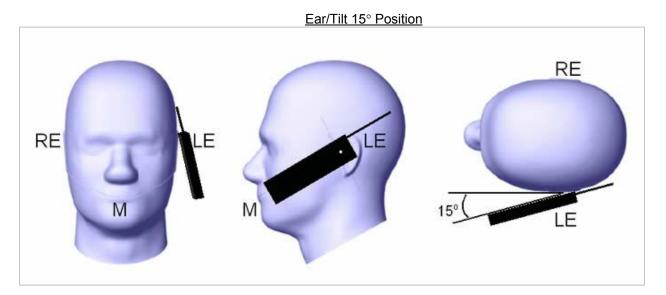
Cheek / Touch Position

4.2 EAR/TILT POSITION

With the handset aligned in the "Cheek/Touch Position":

- i. If the earpiece of the handset is not in full contact with the phantom's ear spacer (in the "Cheek/Touch position") and the peak SAR location for the "Cheek/Touch" position is located at the ear spacer region or corresponds to the earpiece region of the handset, the device should be returned to the "initial ear position" by rotating it away from the mouth until the earpiece is in full contact with the ear spacer.
- ii. (otherwise) The handset should be moved (translated) away from the cheek perpendicular to the line passes through both "ear reference points" (note: one of these ear reference points may not physically exist on a split head model) for approximate 2-3 cm. While it is in this position, the device handset is tilted away from the mouth with respect to the "test device reference point" until the inside angle between the vertical centerline on the front surface of the phone and the horizontal line passing through the ear reference point is by 15°. After the tilt, it is then moved (translated) back toward the head perpendicular to the line passes through both "ear reference points" until the device touches the phantom or the ear spacer. If the antenna touches the head first, the positioning process should be repeated with a tilt angle less than 15° so that the device and its antenna would touch the phantom simultaneously. This test position may require a device holder or positioner to achieve the translation and tilting with acceptable positioning repeatability.

If a device is also designed to transmit with its keypad cover closed for operating in the head position, such positions should also be considered in the SAR evaluation. The device should be tested on the left and right side of the head phantom in the "Cheek/Touch" and "Ear/Tilt" positions. When applicable, each configuration should be tested with the antenna in its fully extended and fully retracted positions. These test configurations should be tested at the high, middle and low frequency channels of each operating mode; for example, AMPS, CDMA, and TDMA. If the SAR measured at the middle channel for each test configuration (left, right, Cheek/Touch, Tilt/Ear, extended and retracted) is at least 3.0 dB lower than the SAR limit, testing at the high and low channels is optional for such test configuration(s). If the transmission band of the test device is less than 10 MHz, testing at the high and low frequency channels is optional.



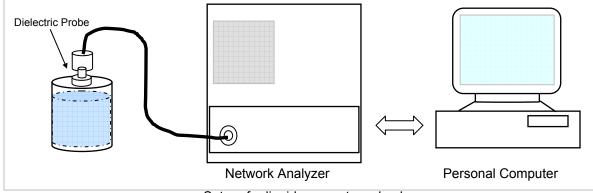
4.3 TEST POSITIONS FOR BODY-WORN AND OTHER SIMILAR CONFIGURATIONS

Without the belt-clips or holsters

Body-worn accessories may not always be supplied or available as options for some devices that are intended to be authorized for body-worn use. A separation distance of 1.5 cm between the back of the device and a flat phantom is recommended for testing body-worn SAR compliance under such circumstances. Other separation distances may be used, but they should not exceed 2.5 cm. In these cases, the device may use body-worn accessories that provide a separation distance greater than that tested for the device provided however that the accessory contains no metallic components.

5 SIMULATING LIQUID PARAMETERS CHECK

The simulating liquids should be checked at the beginning of a series of SAR measurements to determine of the dielectric parameters are within the tolerances of the specified target values. The relative permittivity and conductivity of the tissue material should be within \pm 5% of the values given in the table below.



Set-up for liquid parameters check

Reference Values of Tissue Dielectric Parameters for Head and Body Phantom (for 150 – 3000 MHz and 5800 MHz)

The head tissue dielectric parameters recommended by the IEEE SCC-34/SC-2 in IEEE Standard 1528 have been incorporated in the following table. These head parameters are derived from planar layer models simulating the highest expected SAR for the dielectric properties and tissue thickness variations in a human head. Other head and body tissue parameters that have not been specified in P1528 are derived from the tissue dielectric parameters computed from the 4-Cole-Cole equations and extrapolated according to the head parameters specified in IEEE Standard 1528.

Target Frequency (MHz)	He	ad	Bo	dy
raiger requency (winz)	ε _r	σ (S/m)	ε _r	σ (S/m)
150	52.3	0.76	61.9	0.80
300	45.3	0.87	58.2	0.92
450	43.5	0.87	56.7	0.94
835	41.5	0.90	55.2	0.97
900	41.5	0.97	55.0	1.05
915	41.5	0.98	55.0	1.06
1450	40.5	1.20	54.0	1.30
1610	40.3	1.29	53.8	1.40
1800 – 2000	40.0	1.40	53.3	1.52
2450	39.2	1.80	52.7	1.95
3000	38.5	2.40	52.0	2.73
5800	35.3	5.27	48.2	6.00

(ε_r = relative permittivity, σ = conductivity and ρ = 1000 kg/m³)

5.1 SIMULATING LIQUID PARAMETER CHECK RESULT

Simulating Liquid Dielectric Parameter Check Result @ Head 2450 MHz

Room Ambient Temperature = 23°C; Relative humidity =40%

Measured by: Jonathan King

$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$				Parameters	Measured	Target	Deviation (%)	Limit (%)	
24502215151010101010101010Liquid CheckAmbient temperature: 23 deg. C; Liquid temperature: 22 deg CJanuary 31, 2008 09:53 AMFrequencye'e''240000000.38.352213.1847240500000.38.293713.21652410000000.38.270113.22392420000000.38.245213.2461243000000.38.217913.2668243000000.38.185413.3003244500000.38.124513.3246245000000.38.158013.1122465000000.38.16313.3112246000000.38.158013.312246000000.38.090113.3497246000000.38.051013.3756247000000.38.010513.3921248000000.38.010513.3921248000000.37.982213.4099248500000.37.903113.4671The conductivity (σ) can be given as: $\sigma = \sigma \varepsilon_0 e'' = 2 \pi f \varepsilon_0 e''$ where $f = target f^* 10^6$ $d^* = 2 \pi f \varepsilon_0 e''$	f (MHz) Temp. (°C)	Depth (cm)			T drameters	Medbared		Deviation (70)	Ennic (70)
e"13.3246Conductivity (g):1.816101.800.89 ± 5 Liquid CheckAmbient temperature:23 deg. C; Liquid temperature:22 deg CJanuary 31, 2008 09:53 AMFrequencye"e"240000000.38.352213.18472405000000.38.293713.21652415000000.38.293713.21652420000000.38.245213.24612425000000.38.245213.26682435000000.38.194913.2905244000000.38.158013.3112245000000.38.158013.3112245000000.38.165413.30032445000000.38.165413.3246245000000.38.090113.3497246000000.38.051013.3756247000000.38.036413.3710247500000.38.010513.3921248000000.37.954013.44932485000000.37.93113.4671The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e" = 2 \pi f \varepsilon_{\theta} e"$ where $f = target f* 10^{6}$	2450 22	15	e'	38.1245	Relative Permittivity (ε_r):	38.1245	39.2	-2.74	± 5
Ambient temperature: 23 deg. C; Liquid temperature: 22 deg C January 31, 2008 09:53 AM Frequency e' e" e" 240000000. 38.3522 13.1847 2405000000. 38.3163 13.1909 241000000. 38.2937 13.2165 2415000000. 38.2701 13.2239 242000000. 38.2452 13.2461 2425000000. 38.2452 13.2461 2435000000. 38.1949 13.2905 2440000000. 38.1854 13.3003 2445000000. 38.1854 13.3003 2445000000. 38.1854 13.3003 2445000000. 38.0901 13.3497 246000000. 38.091 13.3497 246000000. 38.091 13.3756 2475000000. 38.0510 13.3756 2475000000. 38.015 13.3921 248000000. 37.9822 13.4099 2485000000. 37.9822 13.4099 2485000000. 37.990 13.4314 249000000. 37.9540 13.4493 2485000000. 37.9540 13.4493 2495000000. 37.901 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^{6}$	2430 22	15	e"	13.3246	Conductivity (σ):	1.81610	1.80	0.89	± 5
Ambient temperature: 23 deg. C; Liquid temperature: 22 deg C January 31, 2008 09:53 AM Frequency e' e" e" 240000000. 38.3522 13.1847 2405000000. 38.3163 13.1909 241000000. 38.2937 13.2165 2415000000. 38.2701 13.2239 242000000. 38.2452 13.2461 2425000000. 38.2452 13.2461 2435000000. 38.1949 13.2905 2440000000. 38.1854 13.3003 2445000000. 38.1854 13.3003 2445000000. 38.1854 13.3003 2445000000. 38.0901 13.3497 246000000. 38.091 13.3497 246000000. 38.091 13.3756 2475000000. 38.0510 13.3756 2475000000. 38.015 13.3921 248000000. 37.9822 13.4099 2485000000. 37.9822 13.4099 2485000000. 37.990 13.4314 249000000. 37.9540 13.4493 2485000000. 37.9540 13.4493 2495000000. 37.901 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^{6}$								•	
January 31, 2008 09:53 AM Frequency e' e" 2400000000. 38.3522 13.1847 2405000000. 38.3163 13.1909 2410000000. 38.2937 13.2165 2415000000. 38.2701 13.2239 2420000000. 38.2452 13.2461 2425000000. 38.2260 13.2582 243000000. 38.12179 13.2668 2435000000. 38.1854 13.3003 2445000000. 38.1854 13.3003 2445000000. 38.1580 13.3112 245000000. 38.1245 13.3246 2455000000. 38.0901 13.3497 246000000. 38.0799 13.3576 2465000000. 38.0364 13.3710 2475000000. 38.0364 13.3710 2475000000. 38.0105 13.3921 248000000. 37.9822 13.4099 2485000000. 37.9822 13.4099 2485000000. 37.9540 13.4314 2495000000. 37.9540 13.4314 2495000000. 37.9165 13.4587 250000000. 37.9165 13.4587 260000000. 37.9165 13.4587 2600000000. 37.9165 13.4587 26000000000000000000000000000000000000	Liquid Check								
Frequencye'e''240000000 38.3522 13.1847 240500000 38.3163 13.1909 241000000 38.2937 13.2165 2415000000 38.2701 13.2239 242000000 38.2452 13.2461 2425000000 38.2452 13.2461 2425000000 38.2452 13.2668 2435000000 38.179 13.2905 2440000000 38.1580 13.3112 245000000 38.1580 13.3112 245000000 38.0901 13.3497 246000000 38.0510 13.3756 2465000000 38.0364 13.3710 2475000000 38.0364 13.3710 2475000000 37.9822 13.4099 2485000000 37.9790 13.4314 249000000 37.9165 13.4587 250000000 37.9165 13.4587 250000000 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^6$ V^{0}	Ambient temperat	ure: 23 deg	g. C	; Liquid	temperature: 22 deg	С			
240000000. 38.3522 13.1847 240500000. 38.3163 13.1909 241000000. 38.2937 13.2165 2415000000. 38.2701 13.2239 242000000. 38.2452 13.2461 2425000000. 38.2179 13.2668 2435000000. 38.1949 13.2905 244000000. 38.1854 13.3003 2445000000. 38.1854 13.3003 2445000000. 38.1245 13.3246 2455000000. 38.0901 13.3756 246000000. 38.091 13.3756 246000000. 38.0510 13.3756 246000000. 38.0510 13.3756 2475000000. 38.054 13.3921 2486000000. 37.9822 13.4099 2485000000. 37.9790 13.4314 249000000. 37.9790 13.4314 249000000. 37.9165 13.3493 248500000. 37.9165 13.4493 249500000. 37.9165 13.4493 249500000. 37.9165 13.4493 249500000. 37.9165 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e^{\mu} = 2 \pi f \varepsilon_{\theta} e^{\mu}$ where $f = target f^* 10^{6}$	January 31, 2008	09:53 AM							
240500000. 38.3163 13.1909 241000000. 38.2937 13.2165 2415000000. 38.2701 13.2239 242000000. 38.2452 13.2461 2425000000. 38.2452 13.2668 243000000. 38.1949 13.2905 244000000. 38.1854 13.3003 2445000000. 38.1854 13.3003 2445000000. 38.1580 13.3112 245000000. 38.0901 13.3497 246000000. 38.0799 13.3576 2465000000. 38.0510 13.3756 247000000. 38.0510 13.3756 247500000. 38.0105 13.3921 2485000000. 37.922 13.4099 2485000000. 37.9822 13.4099 2485000000. 37.9790 13.4314 249000000. 37.9750 13.4493 249500000. 37.9165 13.3497 249500000. 37.9165 13.4493 249500000. 37.9165 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e^{\mu} = 2 \pi f \varepsilon_{\theta} e^{\mu}$ where $f = target f^* 10^{6}$. ,	e'			e"				
241000000. 38.2937 13.2165 241500000. 38.2701 13.2239 242000000. 38.2452 13.2461 242500000. 38.2452 13.2682 243000000. 38.1949 13.2905 244000000. 38.1854 13.3003 2445000000. 38.1580 13.3112 245000000. 38.1245 13.3246 245500000. 38.0901 13.3497 246000000. 38.0901 13.3497 246000000. 38.0510 13.3756 2465000000. 38.0105 13.3921 2475000000. 38.0105 13.3921 248000000. 37.9822 13.4099 2485000000. 37.9540 13.4493 249500000. 37.9165 13.4587 25000000. 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e^{n} = 2 \pi f \varepsilon_{\theta} e^{n}$ where $f = target f^* 10^6$	2400000000.	38.	.35	22	13.1847				
2415000000. 38.2701 13.2239 242000000. 38.2452 13.2461 2425000000. 38.2260 13.2582 243000000. 38.1949 13.2905 2440000000. 38.1854 13.3003 2445000000. 38.1580 13.3112 245000000. 38.1245 13.3246 2455000000. 38.0901 13.3497 2460000000. 38.0799 13.3576 2465000000. 38.0510 13.3756 247000000. 38.0105 13.3921 248000000. 37.9822 13.4099 2485000000. 37.9790 13.4314 249000000. 37.9540 13.4493 249500000. 37.9165 13.4587 25000000. 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^{\delta}$	2405000000.	38.	.31	63	13.1909				
242000000. 38.2452 13.2461 242500000. 38.2260 13.2582 243000000. 38.2179 13.2668 243500000. 38.1949 13.2905 244000000. 38.1854 13.3003 2445000000. 38.1858 13.3112 245000000. 38.0901 13.3497 246000000. 38.0799 13.3576 246500000. 38.0510 13.3756 247000000. 38.0364 13.3710 247500000. 38.0105 13.3921 248000000. 37.9822 13.4099 248500000. 37.9790 13.4314 249000000. 37.9540 13.4493 249500000. 37.9165 13.4587 25000000. 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e^{n} = 2 \pi \int \varepsilon_{\theta} e^{n}$ where $f = target f^* l 0^6$									
242500000 38.2260 13.2582 243000000 38.2179 13.2668 243500000 38.1949 13.2905 244000000 38.1854 13.3003 2445000000 38.1580 13.3112 245000000 38.1245 13.3246 2455000000 38.0901 13.3497 246000000 38.0799 13.3576 246500000 38.0510 13.3756 247000000 38.0105 13.3921 248000000 37.9822 13.4099 248500000 37.9790 13.4314 249000000 37.9540 13.493 249500000 37.9165 13.4587 25000000 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^6$ ϕ^{0}	2415000000.	38.	.27	01	13.2239				
243000000. 38.2179 13.2668 243500000. 38.1949 13.2905 244000000. 38.1854 13.3003 2445000000. 38.1580 13.3112 245000000. 38.1245 13.3246 2455000000. 38.0901 13.3497 246000000. 38.0799 13.3576 246500000. 38.0510 13.3756 247000000. 38.0364 13.3710 247500000. 38.0105 13.3921 248000000. 37.9822 13.4099 248500000. 37.9790 13.4314 249000000. 37.9540 13.4587 250000000. 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e''= 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^6$ $= 4000000000000000000000000000000000000$		38.	.24	52					
243500000. 38.1949 13.2905 244000000. 38.1854 13.3003 2445000000. 38.1580 13.3112 245000000. 38.0901 13.3497 246000000. 38.0799 13.3576 2465000000. 38.0510 13.3756 2470000000. 38.0364 13.3710 2475000000. 38.0105 13.3921 2480000000. 37.9822 13.4099 2485000000. 37.9790 13.4314 249000000. 37.9540 13.4493 2495000000. 37.9165 13.4587 250000000. 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^{\phi}$	2425000000.	38.	.22	60	13.2582				
244000000 . 38.1854 13.3003 244500000 . 38.1580 13.3112 245000000 . 38.1245 13.3246 2455000000 . 38.0901 13.3497 2460000000 . 38.0799 13.3576 2465000000 . 38.0510 13.3756 2470000000 . 38.0364 13.3710 2475000000 . 38.0105 13.3921 2480000000 . 37.9822 13.4099 2485000000 . 37.9790 13.4314 2490000000 . 37.9540 13.4587 250000000 . 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^6$ 40^6									
$2445000000.$ 38.1580 13.3112 $2450000000.$ 38.0901 13.3246 $2455000000.$ 38.0901 13.3497 $2460000000.$ 38.0799 13.3576 $2465000000.$ 38.0510 13.3756 $2470000000.$ 38.0364 13.3710 $2475000000.$ 38.0105 13.3921 $2480000000.$ 37.9822 13.4099 $2485000000.$ 37.9790 13.4314 $2490000000.$ 37.9540 13.493 $2495000000.$ 37.9165 13.4587 $250000000.$ 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e^{\mu} = 2 \pi f \varepsilon_{\theta} e^{\mu}$ where $f = target f^* 10^6$ 10^6									
245000000.38.124513.3246 2455000000.38.090113.3497246000000.38.079913.35762465000000.38.051013.37562470000000.38.036413.37102475000000.38.010513.39212480000000.37.982213.40992485000000.37.979013.4314249000000.37.954013.4587250000000.37.916513.4587250000000.37.903113.4671The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_0 e'' = 2 \pi f \varepsilon_0 e''$ where $f = target f^* 10^6$									
$2455000000.$ 38.0901 13.3497 $2460000000.$ 38.0799 13.3576 $2465000000.$ 38.0510 13.3756 $2470000000.$ 38.0364 13.3710 $2475000000.$ 38.0105 13.3921 $2480000000.$ 37.9822 13.4099 $2485000000.$ 37.9790 13.4314 $2490000000.$ 37.9540 13.4493 $2495000000.$ 37.9165 13.4587 $250000000.$ 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^6$	2445000000.	38.	.15	80	13.3112				
246000000.38.079913.35762465000000.38.051013.3756247000000.38.036413.3710247500000.38.010513.3921248000000.37.982213.40992485000000.37.979013.43142490000000.37.954013.4587250000000.37.903113.4671The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_0 e'' = 2 \pi f \varepsilon_0 e''$ where $f = target f^* 10^6$		38.	.12	45	13.3246				
246500000.38.051013.3756247000000.38.036413.3710247500000.38.010513.3921248000000.37.982213.40992485000000.37.979013.43142490000000.37.954013.44932495000000.37.916513.4587250000000.37.903113.4671The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^6$									
$247000000.$ 38.0364 13.3710 $247500000.$ 38.0105 13.3921 $248000000.$ 37.9822 13.4099 $2485000000.$ 37.9790 13.4314 $2490000000.$ 37.9540 13.4493 $2495000000.$ 37.9165 13.4587 $250000000.$ 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^{6}$									
$2475000000.$ 38.0105 13.3921 $2480000000.$ 37.9822 13.4099 $2485000000.$ 37.9790 13.4314 $2490000000.$ 37.9540 13.4493 $2495000000.$ 37.9165 13.4587 $250000000.$ 37.9031 13.4671 The conductivity (σ) can be given as: $\boldsymbol{\sigma} = \boldsymbol{\omega} \boldsymbol{\varepsilon}_{\theta} \mathbf{e}'' = 2 \pi f \boldsymbol{\varepsilon}_{\theta} \mathbf{e}''$ where $f = target f^* 10^6$									
248000000.37.982213.4099248500000.37.979013.4314249000000.37.954013.44932495000000.37.916513.45872500000000.37.903113.4671The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e''= 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^6$		38.	.03	64					
2485000000. 37.9790 13.4314 2490000000. 37.9540 13.4493 2495000000. 37.9165 13.4587 2500000000. 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_0 e''= 2 \pi f \varepsilon_0 e''$ where $f = target f^* 10^6$									
249000000. 37.9540 13.4493 249500000. 37.9165 13.4587 250000000. 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_0 e'' = 2 \pi f \varepsilon_0 e''$ where $f = target f^* 10^6$									
2495000000. 37.9165 13.4587 2500000000. 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f * 10^6$					13.4314				
250000000. 37.9031 13.4671 The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_{\theta} e'' = 2 \pi f \varepsilon_{\theta} e''$ where $f = target f^* 10^{6}$									
The conductivity (σ) can be given as: $\sigma = \omega \varepsilon_0 e'' = 2 \pi f \varepsilon_0 e''$ where $f = target f^* 10^6$.9165						
$\sigma = \omega \varepsilon_0 e'' = 2 \pi f \varepsilon_0 e''$ where $f = target f^* 10^6$	2500000000.	37.	.90	31	13.4671				
where $f = target f * 10^6$	The conductivity (σ) can be given as:								
	$\sigma = \omega \varepsilon_{\theta} \mathbf{e}'' = 2 \pi f \varepsilon_{\theta} \mathbf{e}''$								
$\epsilon_0 = 8.854 * 10^{-12}$									
	E _0 = 8.854	* 10 ⁻¹²							

Simulating Liquid Dielectric Parameter Check Result @ Muscle 2450 MHz

Room Ambient Temperature = 23°C; Relative humidity = 40%

Measured by: Jonathan King

Simulating Liquid					Parameters	Measured	Target	Deviation (%)	Limit (%)
f (MHz)	Temp. (°C)	Depth (cm)			T arameters	Measureu		Deviation (70)	Linit (70)
2450	22	15	e'	54.3001	Relative Permittivity (ε_r):	54.3001	52.7	3.04	± 5
2100		10	e"	14.8217	Conductivity (σ):	2.02015	1.95	3.60	± 5
Liquid Ch	neck								
Ambient	temperat	ure: 23.0 d	leg	. C; Liqu	id temperature: 22.0 d	deg C			
January 3	31, 2008	12:48 PM							
Frequence		e'			e"				
2400000	000.	53	.82	230	14.2832				
2405000	000.	53	.76	643	14.4099				
2410000	000.	53	.73	898	14.5114				
2415000	000.	53	.74	124	14.6092				
2420000	000.	53	.76	64	14.6869				
2425000	000.	53	.83	319	14.7416				
2430000	000.	53	.92	293	14.7898				
2435000	000.	54	.0527 14.8269						
2440000	000.	54	.15	572	14.8372				
2445000	000.	54	.23	349	14.8151				
2450000	000.	54	.30	001	14.8217				
2455000	000.	54	.35	500	14.7844				
2460000	000.	54	.37	736	14.7101				
2465000	000.	54	.38	393	14.6301				
2470000	000.	54	.32	246	14.5566				
2475000	000.	54	.29	903	14.4816				
2480000	000.	54	.23	355	14.4356				
2485000	000.	54	.16	650	14.4159				
2490000	000.	54	.06	672	14.4227				
2495000	000.	53	3.9662		14.4587				
2500000	000.	53	.82	236	14.5250				
The conductivity (σ) can be given as:									
$\sigma = \omega \varepsilon_{\theta} \mathbf{e}'' = 2 \pi f \varepsilon_{\theta} \mathbf{e}''$									
	f = target f								
EO	= 8.854 *	* 10 ⁻¹²							

6 SYSTEM PERFORMANCE CHECK

The system performance check is performed prior to any usage of the system in order to guarantee reproducible results. The system performance check verifies that the system operates within its specifications of $\pm 10\%$.

System Performance Check Measurement Conditions

- The measurements were performed in the flat section of the SAM twin phantom filled with Head simulating liquid of the following parameters.
- The DASY4 system with an Isotropic E-Field Probe EX3DV3-SN: 3554 was used for the measurements.
- The dipole was mounted on the small tripod so that the dipole feed point was positioned below the center marking of the flat phantom section and the dipole was oriented parallel to the body axis (the long side of the phantom). The standard measuring distance was 10 mm (above 1 GHz) and 15 mm (below 1 GHz) from dipole center to the simulating liquid surface.
- The coarse grid with a grid spacing of 15 mm was aligned with the dipole. For 5 GHz band - The coarse grid with a grid spacing of 10 mm was aligned with the dipole.
- Special 5 x 5 x 7 fine cube was chosen for cube integration(dx=dy=7.5mm; dz=5mm).
 For 5 GHz band Special 8x8x8 fine cube was chosen for cube integration(dx=dy=4.3mm; dz=3mm)
- Distance between probe sensors and phantom surface was set to 4 mm.
 For 5 GHz band Distance between probe sensors and phantom surface was set to 2.0mm
- The dipole input power (forward power) was 250 mW±3%.
- The results are normalized to 1 W input power.

IEEE Standard 1528-2003 Recommended Reference Value.

Frequency (MHz)	Distance (mm)	1g SAR [W/kg]	10g SAR [W/kg]
300	15	3.0	2.0
450	15	4.9	3.3
835	15	9.5	6.2
900	15	10.8	6.9
1450	10	29.0	16.0
1800	10	38.1	19.8
1900	10	39.7	20.5
2000	10	41.1	21.1
2450	10	52.4	24.0
3000	10	63.8	25.7

Note: All SAR values normalized to 1 W forward power.

6.1 SYSTEM PERFORMANCE CHECK RESULTS

System Validation Dipole: D2450V2 SN: 706

Date: January 31, 2008

Ambient Temperature = 23°C; Relative humidity = 40%

Measured by: Jonathan King

Head Simulating Liquid			SAR (mW/g)		Normalized	Torgot	Deviation	Limit
f (MHz)	Temp. (°C)	Depth (cm)	5AN	(mw/g)	to 1 W	Target	(%)	(%)
2450	22	15	1g	13.30	53.2	52.4	1.53	± 10
2450	22	15	10g	5.89	23.56	24.0	-1.83	± 10

7 SAR MEASURMENT PROCEDURE

A summary of the procedure follows:

- a) A measurement of the SAR value at a fixed location is used as a reference value for assessing the power drop of the EUT. The SAR at this point is measured at the start of the test, and then again at the end of the test.
- b) The SAR distribution at the exposed flat section of the flat phantom is measured at a distance of 4 mm from the inner surface of the shell. The area covers the entire dimension of the EUT and the horizontal grid spacing is 15 mm x 15 mm. Based on this data, the area of the maximum absorption is determined by Spline interpolation. The first Area Scan covers the entire dimension of the EUT to ensure that the hotspot was correctly identified.

For 5 GHz band - The SAR distribution at the exposed flat section of the flat phantom is measured at a distance of 2.0 mm from the inner surface of the shell. The area covers the entire dimension of the EUT and the horizontal grid spacing is 10 mm x 10 mm. Based on this data, the area of the maximum absorption is determined by Spline interpolation. The first Area Scan covers the entire dimension of the EUT to ensure that the hotspot was correctly identified.

c) Around this point, a volume of X=Y= 30 and Z=21 mm is assessed by measuring 5 x 5 x 7 mm points. On the basis of this data set, the spatial peak SAR value is evaluated with the following procedure:

For 5 GHz band - Around this point, a volume of X=Y=24 and Z=20 mm is assessed by measuring 7 x 7 x 9 mm points. On the basis of this data set, the spatial peak SAR value is evaluated with the following procedure:

- (i) The data at the surface are extrapolated, since the centre of the dipoles is 1.2 mm away from the tip of the probe and the distance between the surface and the lowest measuring point is 1.3 mm. The extrapolation is based on a least square algorithm. A polynomial of the fourth order is calculated through the points in z-axes. This polynomial is then used to evaluate the points between the surface and the probe tip.
- (ii) The maximum interpolated value is searched with a straightforward algorithm. Around this maximum the SAR values averaged over the spatial volumes (1 g and 10 g) are computed using the 3D-Spline interpolation algorithm. The 3D-Spline is composed of three one-dimensional splines with the "Not a knot"- condition (in x, y and z-direction). The volume is integrated with the trapezoidal algorithm. One thousand points (10 x 10 x 10) are interpolated to calculate the averages.
- (iii) All neighbouring volumes are evaluated until no neighbouring volume with a higher average value is found.
- (iv) The SAR value at the same location as in Step (a) is again measured to evaluate the actual power drift.

7.1 DASY4 SAR MEASURMENT PROCEDURE

Step 1: Power Reference Measurement

The Power Reference Measurement and Power Drift Measurements are for monitoring the power drift of the device under test in the batch process. The Minimum distance of probe sensors to surface determines the closest measurement point to phantom surface. The minimum distance of probe sensors to surface is 2.1 mm. This distance cannot be smaller than the Distance of sensor calibration points to probe tip as defined in the probe properties (for example, 1.2 mm for an EX3DV3 probe type).

Step 2: Area Scan

The Area Scan is used as a fast scan in two dimensions to find the area of high field values, before doing a fine measurement around the hot spot. The sophisticated interpolation routines implemented in DASY4 software can find the maximum locations even in relatively coarse grids. When an Area Scan has measured all reachable points, it computes the field maximal found in the scanned area, within a range of the global maximum. The range (in dB) is specified in the standards for compliance testing. For example, a 2 dB range is required in IEEE Standard 1528, EN 50361 and IEC 62209 standards, whereby 3 dB is a requirement when compliance is assessed in accordance with the ARIB standard (Japan). If only one Zoom Scan follows the Area Scan, then only the absolute maximum will be taken as reference. For cases where multiple maximums are detected, the number of Zoom Scans has to be increased accordingly.

Step 3: Zoom Scan

Zoom Scans are used to assess the peak spatial SAR values within a cubic averaging volume containing 1 g and 10 g of simulated tissue. The Zoom Scan measures $5 \times 5 \times 7$ points within a cube whose base faces are centered on the maxima found in a preceding area scan job within the same procedure. When the measurement is done, the Zoom Scan evaluates the averaged SAR for 1 g and 10 g and displays these values next to the job's label.

For 5 GHz band – Same as above except the Zoom Scan measures 7 x 7 x 9 points.

Step 4: Power drift measurement

The Power Drift Measurement measures the field at the same location as the most recent power reference measurement within the same procedure, and with the same settings. The Power Drift Measurement gives the field difference in dB from the reading conducted within the last Power Reference Measurement. This allows a user to monitor the power drift of the device under test within a batch process. The measurement procedure is the same as Step 1.

Step 5: Z-Scan

The Z Scan measures points along a vertical straight line. The line runs along the Z-axis of a onedimensional grid. In order to get a reasonable extrapolation, the extrapolated distance should not be larger than the step size in Z-direction.

8 PROCEDURE USED TO ESTABLISH TEST SIGNAL

The following procedures had been used to prepare the EUT for the SAR test.

The cable assembly insertion loss of 11dB (including 10 dB attenuator and 1dB connectors) was entered as an offset in the power meter to allow for direct reading of power.

802.11b		
Channel	Frequency	Average Power
	(MHz)	(dBm)
Low	2412	12.1
Middle	2437	12.2
High	2462	12.3

9 SAR MEASURMENT RESULTS

9.1 HEAD POSITIONS - LEFT HAND SIDE (LHS)

Touch Position Tilt (15°) Position								
802.11b								
Test Position	Channel	f (MHz)	Measured SA 1g (mW/g)		Power Drift (dB)	Extrapolated ¹⁾ SAR 1g (mW/g)		
Touch	1 6 11	2412.0 2437.0 2462.0	0.394		-0.012	0.395		
Tilt (15°)	1 6 11	2412.0 2437.0 2462.0	0.326		0.000	0.326		
process by th measuremer 2) The SAR me mW/g), thus	ne DASY4 system nt process. easured at the mid testing at low & hi	can be scaled dle channel for gh channel is o	up by the this configutional.	Power drift to guration is at	o determine the SA least 3 dB lower ((d at the end of the measureme AR at the beginning of the 0.8 mW/g) than SAR limit (1.6 imum SAR location of the EUT		

Please see attachments for the detailed measurement data and plots showing the maximum SAR location of the EUT.
 The battery was fully charged in accordance with manufacture's instructions prior to SAR measurements.

9.2 HEAD POSITIONS - RIGHT HAND SIDE (RHS)



Touch Position

Tilt (15°) Position

802.11b

Test Position	Channel	f (MHz)	Measured SAR 1g (mW/g)	Power Drift (dB)	Extrapolated ¹⁾ SAR 1g (mW/g)	
	1	2412.0	0.414	-0.028	0.417	
Touch	6	2437.0	0.417	-0.016	0.419	
	11	2462.0	0.452	-0.010	0.453	
Tilt (15°)	1	2412.0				
	6	2437.0	0.340	-0.141	0.351	
	11	2462.0				

Notes:

 The exact method of extrapolation is Measured SAR x 10⁽⁻drift/10). The SAR reported at the end of the measurement process by the DASY4 system can be scaled up by the Power drift to determine the SAR at the beginning of the measurement process.

2) The SAR measured at the middle channel for this configuration is at least 3 dB lower (0.8 mW/g) than SAR limit (1.6 mW/g), thus testing at low & high channel is optional.

3) Please see attachments for the detailed measurement data and plots showing the maximum SAR location of the EUT.

4) The battery was fully charged in accordance with manufacture's instructions prior to SAR measurements.

9.3 BODY-WORN POSITION - NO SEPARATION

Charles and the second second							
-					and the second		
	v		CD Eacing Up				
902 115			CD Facing Up				
802.11b	Channel		CD Facing Up	Power Drift	Extrapolated ¹⁾ SAR		
802.11b Test Position	Channel	f (MHz)	Measured SAR 1g (mW/g)	(dB)	Extrapolated ¹⁾ SAR 1g (mW/g)		
Test Position	1	f (MHz) 2412.0	Measured SAR 1g (mW/g) 1.240	(dB) 0.000	1g (mW/g) 1.240		
Test Position	1	f (MHz) 2412.0	Measured SAR 1g (mW/g) 1.240	(dB) 0.000	1g (mW/g) 1.240		
		f (MHz)	Measured SAR 1g (mW/g)	(dB)	1g (mW/g)		

The battery was fully charged in accordance with manufacture's instructions prior to SAR measurements.
 LCD facing down position was skipped due to significantly lower SAR value.

10 MEASURMENT UNCERTAINTY

10.1 MEASURMENT UNCERTAINTY FOR 300 MHz - 3000 MHz

Uncortainty component	Tel (+0()	Probe	Div.	0: (4)	C: (40 m)	Std. Unc.(±%)		
Uncertainty component	Tol. (±%)	Dist.	Div.	Ci (1g)	Ci (10g)	Ui (1g)	Ui(10g)	
Measurement System								
Probe Calibration	4.80	Ν	1	1	1	4.80	4.80	
Axial Isotropy	4.70	R	1.732	0.707	0.707	1.92	1.92	
Hemispherical Isotropy	9.60	R	1.732	0.707	0.707	3.92	3.92	
Boundary Effects	1.00	R	1.732	1	1	0.58	0.58	
Linearity	4.70	R	1.732	1	1	2.71	2.71	
System Detection Limits	1.00	R	1.732	1	1	0.58	0.58	
Readout Electronics	1.00	Ν	1	1	1	1.00	1.00	
Response Time	0.80	R	1.732	1	1	0.46	0.46	
Integration Time	2.60	R	1.732	1	1	1.50	1.50	
RF Ambient Conditions - Noise	1.59	R	1.732	1	1	0.92	0.92	
RF Ambient Conditions - Reflections	0.00	R	1.732	1	1	0.00	0.00	
Probe Positioner Mechnical Tolerance	0.40	R	1.732	1	1	0.23	0.23	
Probe Positioning With Respect to Phantom Shell	2.90	R	1.732	1	1	1.67	1.67	
Extrapolation, interpolation, and integration algorithms for								
max. SAR evaluation	3.90	R	1.732	1	1	2.25	2.25	
Test sample Related								
Test Sample Positioning	1.10	Ν	1	1	1	1.10	1.10	
Device Holder Uncertainty	3.60	Ν	1	1	1	3.60	3.60	
Power and SAR Drift Measurement	5.00	R	1.732	1	1	2.89	2.89	
Phantom and Tissue Parameters								
Phantom Uncertainty	4.00	R	1.732	1	1	2.31	2.31	
Liquid Conductivity - Target	5.00	R	1.732	0.64	0.43	1.85	1.24	
Liquid Conductivity - Meas.	8.60	N	1	0.64	0.43	5.50	3.70	
Liquid Permittivity - Target	5.00	R	1.732	0.6	0.49	1.73	1.41	
Liquid Permittivity - Meas.	3.30	N	1	0.6	0.49	1.98	1.62	
Combined Standard Uncertainty	RSS					11.44	10.49	
Expanded Uncertainty (95% Confidence Interval)			K=2			22.87	20.98	
Notesfor table								
1. Tol tolerance in influence quaitity								
2. N - Nomal								
3. R - Rectangular								
4. Div Divisor used to obtain standard uncertainty								

5. Ci - is te sensitivity coefficient

11 EQUIPMENT LIST AND CALIBRATION

Name of Equipment	Manufacturer	Type/Model	Serial Number	ММ		Due date Year
Robot - Six Axes	Stäubli	RX90BL	N/A			N/A
Robot Remote Control	Stäubli	CS7MB	3403-91535			N/A
DASY4 Measurement Server	SPEAG	SEUMS001BA	1041			N/A
Probe Alignment Unit	SPEAG	LB (V2)	261			N/A
SAM Phantom (SAM1)	SPEAG	QD000P40CA	1185			N/A
SAM Phantom (SAM2)	SPEAG	QD000P40CA	1050			N/A
Oval Flat Phantom (ELI 4.0)	SPEAG	QD OVA001 B	1003			N/A
Electronic Probe kit	HP	85070C	N/A			N/A
S-Parameter Network Analyzer	Agilent	8753ES-6	US39173569	2	14	2008
E-Field Probe	SPEAG	EX3DV4	3554	4	24	2008
Thermometer	ERTCO	639-1S	1718	8	30	2008
Data Acquisition Electronics	SPEAG	DAE3 V1	500	11	16	2008
System Validation Dipole	SPEAG	D2450V2	706	4	27	2008
Signal Generator	R&S	SMP 04	DE34210	2	16	2009
Power Meter	Giga-tronics	8651A	8651404	4	3	2008
Power Sensor	Giga-tronics	80701A	1834588	4	17	2008
Amplifier	Mini-Circuits	ZHL-42W	D072701-5			N/A
Simulating Liquid	CCS	H2450	N/A	Withi	n 24 h	irs of first test
Simulating Liquid	CCS	M2450	N/A	Withi	n 24 h	rs of first test

12 PHOTOS







13 ATTACHMENTS

No.	Contents	No. Of Pages
1	System Performance Check Plots	2
2	SAR Test Plots	11
3	Certificate of E-Field Probe - EX3DV4SN3554	10
4	Certificate of System Validation Dipole - D2450 SN:706	9

END OF REPORT